TOSHIBA PHOTOCOUPLER InGaAs IRED & PHOTO-TRANSISTOR

TLP293

Power Supplies Programmable Controllers Hybrid ICs

TLP293 consists of a low input type photo transistor optically coupled to an InGaAs infrared emitting diode.

TLP293 is housed in the SO4 package, very small and thin coupler. Since TLP293 is guaranteed wide operating temperature (Ta=-55 to 125 °C) and high isolation voltage (3750 Vrms), it's suitable for high-density surface mounting applications such as small switching power supplies and programmable controllers.

Collector-Emitter Voltage : 80 V (min) **Current Transfer Ratio** : 50% (min) Rank GB : 100% (min) Isolation Voltage : 3750 Vrms (min) Operation temperature : -55 to 125 °C

UL recognized : UL1577, File No. E67349

: CSA Component Acceptance Service No.5A, cUL approved

File No. E67349

Option (V4)

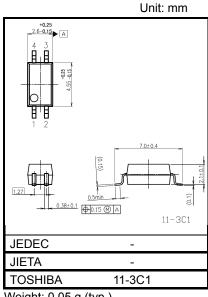
VDE approved : DIN EN 60747-5-5 approved No. 40009347

(Note) When an EN 60747-5-5 approved type is needed, please designate the "Option (V4)"

Construction Mechanical Rating Creepage distance: 5.0mm (min)

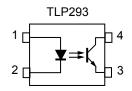
Clearance: 5.0mm (min)

Insultion thickness: 0.4mm (min)



Weight: 0.05 g (typ.)

Pin Configuration



1:ANODE 2:CATHODE 3:EMITTER 4:COLLECTOR

Current Transfer Ratio (CTR) Rank (Unless otherwise specified, Ta = 25°C)

Rank		Current Transfer Ratio IC / IF Min Max			
	Test Condition			Marking Of Classification	Unit
(Note1)					
Blank	I _F = 5 mA, V _{CE} = 5 V	50	600	Blank, YE, GR, GB, BL, Y+,	
Blank	$I_F = 0.5 \text{ mA}, V_{CE} = 5 \text{ V}$	30	000	G, G+, B	
Υ	$I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	50	150	YE	
	$I_F = 0.5 \text{ mA}, V_{CE} = 5 \text{ V}$				
GR	$I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	100	300	GR	
	$I_F = 0.5 \text{ mA}, V_{CE} = 5 \text{ V}$				
GB	GB I _F = 5 mA, V _{CE} = 5 V 100 600		600	GB	
	$I_F = 0.5 \text{ mA}, V_{CE} = 5 \text{ V}$				
BL	$I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	200	600	BL	%
	$I_F = 0.5 \text{ mA}, V_{CE} = 5 \text{ V}$				70
YH	$I_F = 0.5 \text{ mA}, V_{CE} = 5 \text{ V}$	75	150	Y+	
GRL	I _F = 0.5 mA, V _{CE} = 5 V	100	200	G	
GRH	I _F = 0.5 mA, V _{CE} = 5 V	150	300	G+	
BLL	I _F = 0.5 mA, V _{CE} = 5 V	200	400	В	

Note1: Specify both the part number and a rank in this format when ordering

(e.g.) rank GB: TLP293 (GB,E

For safety standard certification, however, specify the part number alone.

(e.g.)TLP293 (GB,E: TLP293

Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25°C)

CHARACTERISTIC		SYMBOL	NOTE	RATING	UNIT
Input forward current		l _F		50	mA
Input forward current derating (Ta≥90°C)		∆I _F / Δ Ta		-1.5	mA /°C
LED	Input forward current (pulsed)	I _{FP}	(Note 2)	1	Α
	Input reverse voltage	V _R		5	٧
	Junction temperature	Tj		125	°C
	Collector-emitter voltage	V _{CEO}		80	٧
~	Emitter-collector voltage	V _{ECO}		7	٧
DETECTOR	Collector current	lc		50	mA
ETE(Collector power dissipation	PC		150	mW
□	Collector power dissipation derating(Ta≥25°C)	ΔΡ _C /ΔΤα		-1.5	mW /°C
	Junction temperature	Tj		125	°C
Оре	rating temperature range	T _{opr}		-55 to 125	°C
Storage temperature range		T _{stg}		-55 to 125	°C
Lead soldering temperature		T _{sol}		260 (10s)	°C
Total package power dissipation		P _T		200	mW
Total package power dissipation derating(Ta≥25°C)		ΔΡ _Τ /ΔΤα		-2.0	mW /°C
Isolation voltage		BVS	(Note3)	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note2: Pulse width $\leq 100 \mu s$, frequency 100Hz

Note3: AC, 1 minute, R.H.≤60%, Device considered a two terminal device: LED side pins shorted together and DETECTOR side pins shorted together.

Electrical Characteristics (Unless otherwise specified, Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
	Input forward voltage	V_{F}	I _F = 10 mA	1.1	1.25	1.4	V
В	Input reverse current	I _R	V _R = 5 V	1	-	5	μΑ
	Input capacitance	C _T	V = 0 V, f = 1 MHz	-	30	-	pF
	Collector-emitter breakdown voltage	V _(BR) CEO	I _C = 0.5 mA	80	-	-	V
'OR	Emitter-collector breakdown voltage	V _{(BR) ECO}	I _E = 0.1 mA	7	-	-	V
ECT	Emitter-collector breakdown voltage Dark current	I _{DARK}	V _{CE} = 48 V	1	0.01	0.08	μΑ
DEI			V _{CE} = 48 V, Ta = 85°C	ı	2	50	μΑ
	Collector-emitter capacitance	C_{CE}	V = 0 V, f = 1 MHz	-	10	-	pF

Coupled Electrical Characteristics (Unless otherwise specified, Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT	
		I _F = 5 mA, V _{CE} = 5 V	50	-	600		
Current transfer ratio	lo / l=	Rank Gl	100	-	600	%	
Current transier ratio	I _C / I _F	I _F = 0.5 mA, V _{CE} = 5 V	50	-	600	70	
		Rank Gl	100	-	600		
Saturated current transfer ratio	1- /1	I _F = 1 mA, V _{CE} = 0.4 V	-	60	-	%	
Saturated current transfer ratio	I _C / I _{F (sat)}	Rank Gl	30	-	600 600 600	70	
		I _C = 2.4 mA, I _F = 8 mA	-	-	0.3		
Collector-emitter saturation voltage	V _{CE} (sat)	I _C = 0.2 mA, I _F = 1 mA	-	0.2	-	V	
		Rank Gl	-	-	0.3		
OFF-state collector current	I _{C (off)}	V _F = 0.7 V, V _{CE} = 48 V	-	-	10	μΑ	

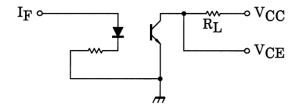
Isolation Characteristics (Unless otherwise specified, Ta = 25°C)

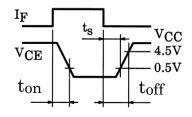
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Total capacitance (input to output)	CS	V _S = 0 V, f = 1 MHz	-	0.8	-	pF
Isolation resistance	R _S	V _S = 500 V, R.H.≤60%	1×10 ¹²	10 ¹⁴	-	Ω
Isolation voltage	BVS	AC , 1 minute	3750	-	-	Vrms
		AC , 1 second, in OIL	-	10000	-	
		DC , 1 minute, in OIL	-	10000	-	Vdc

Switching Characteristics (Unless otherwise specified, Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Rise time	t _r		-	2	-	- μ s
Fall time	t _f	V _{CC} = 10 V, I _C = 2 mA	-	3	-	
Turn-on time	t _{on}	$R_L = 100\Omega$	-	3	-	
Turn-off time	t _{off}		-	3	-	
Turn-on time	t _{on}		-	0.4	-	
Storage time	ts	$R_L = 1.9 \text{ k}\Omega$ (Fig.1) $V_{CC} = 5 \text{ V}, I_F = 16 \text{ mA}$	-	20	-	μS
Turn-off time	toff	766 9 1, 1	-	35	-	
Turn-on time	t _{on}		-	4	-	
Storage time	t _S	$R_L = 4.7 \text{ k}\Omega$ (Fig.1) $V_{CC} = 5 \text{ V}, I_F = 1.6 \text{ mA}$	-	7	-	μS
Turn-off time	t _{off}	00 - 71 - 11-11-11	-	30	-	

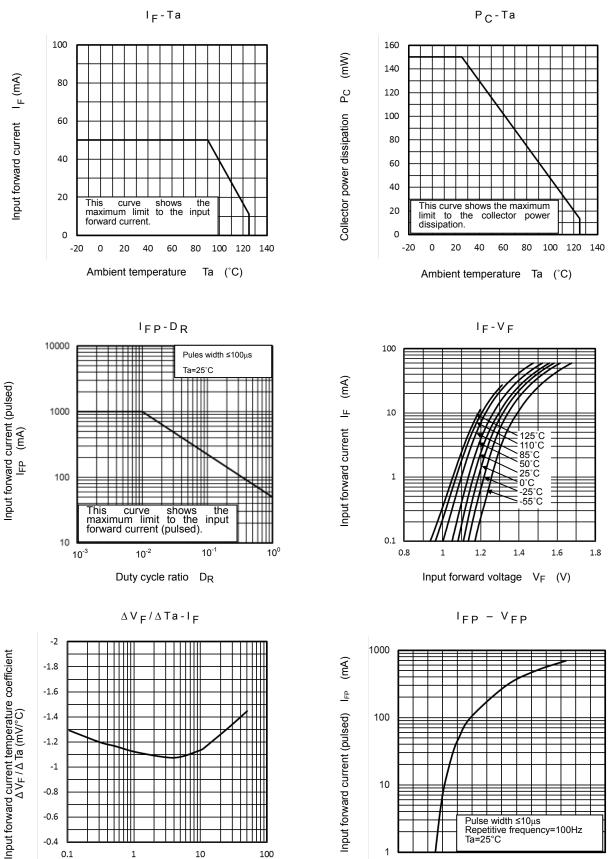
(Fig.1) Switching Time Test Circuit





-0.4 0.1

Characteristics Curves (Note)



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

100

10

Input forward current I_F (mA)

0.6

1.4

1

1.8

Input forward voltage (pulsed) VFP

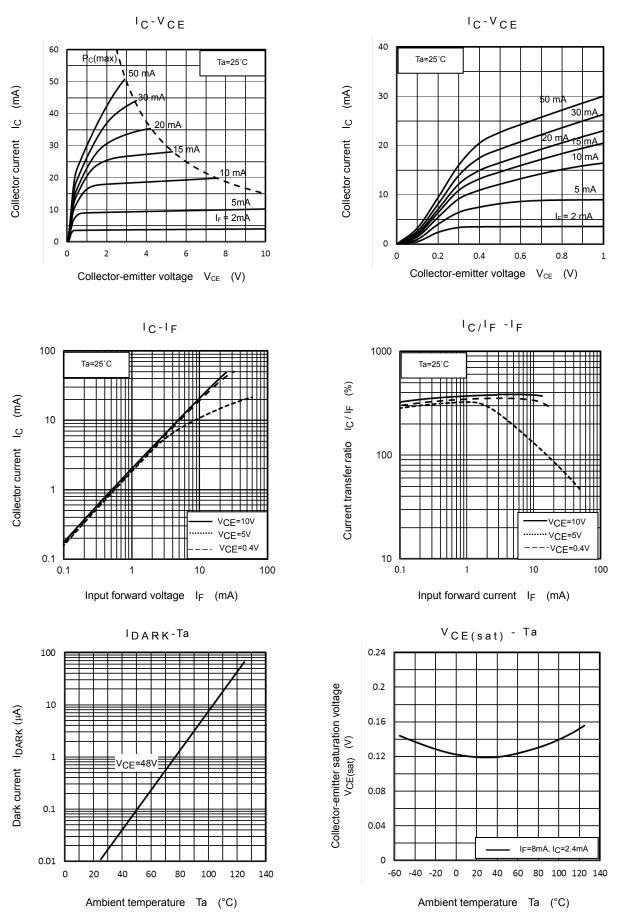
2.2

2.6

3

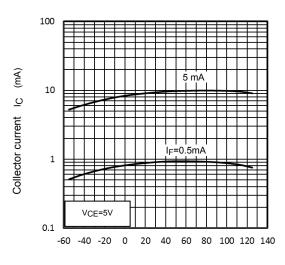
(V)

3.4



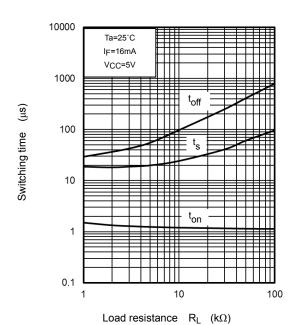
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



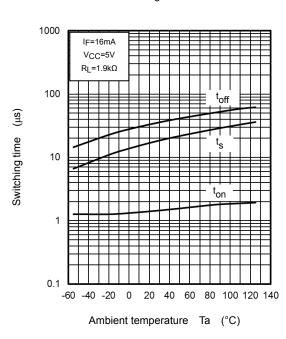


Ambient temperature Ta (°C)

Switching time - R_L



Switching time - Ta



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Soldering and Storage

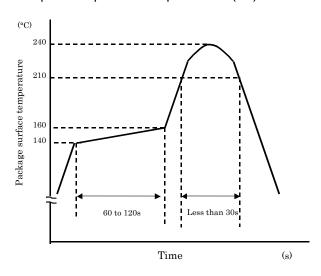
1. Soldering

1.1 Soldering

When using a soldering iron or medium infrared ray/hot air reflow, avoid a rise in device temperature as much as possible by observing the following conditions.

1) Using solder reflow

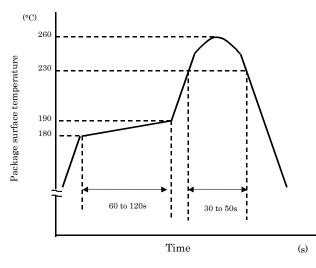
·Temperature profile example of lead (Pb) solder



This profile is based on the device's maximum heat resistance guaranteed value.

Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

·Temperature profile example of using lead (Pb)-free solder



This profile is based on the device's maximum heat resistance guaranteed value.

Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

- 2) Using solder flow (for lead (Pb) solder, or lead (Pb)-free solder)
 - · Please preheat it at 150°C between 60 and 120 seconds.
 - · Complete soldering within 10 seconds below 260°C.
 - ·Flow soldering must be performed once.
- 3) Using a soldering iron

Complete soldering within 10 seconds below 260°C, or within 3 seconds at 350°C. Each pin may be heated at most once.

2. Storage

- 1) Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- 2) Follow the precautions printed on the packing label of the device for transportation and storage.
- 3) Keep the storage location temperature and humidity within a range of 5°C to 35°C and 45% to 75%, respectively.
- 4) Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- 5) Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- 6) When restoring devices after removal from their packing, use anti-static containers.
- 7) Do not allow loads to be applied directly to devices while they are in storage.
- 8) If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

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